

# TLVx369 Cost-Optimized, 800-nA, 1.8-V, Rail-to-Rail I/O Operational Amplifier with Zero-Crossover Distortion

## 1 Features

- Cost-Optimized Precision Amplifier *nanoPower*: 800 nA/Ch (Typ)
- Low Offset Voltage: 400  $\mu$ V (Typ)
- Rail-to-Rail Input and Output
- Zero-Crossover Distortion
- Low Offset Drift: 0.5  $\mu$ V/ $^{\circ}$ C (Typ)
- Gain-Bandwidth Product: 12 kHz
- Supply Voltage: 1.8 V to 5.5 V
- *microSize* Packages: SC70-5, VSSOP-8

## 2 Applications

- Blood Glucose Meters
- Test Equipment
- Low-Power Sensor Signal Conditioning
- Portable Devices

## 3 Description

The TLV369 family of single and dual operational amplifiers represents a cost-optimized generation of 1.8-V nanopower amplifiers.

With the zero-crossover distortion circuitry, these amplifiers feature high linearity over the full common-mode input range with no crossover distortion, enabling true rail-to-rail input and operating from a 1.8-V to 5.5-V single supply. The family is also compatible with industry-standard nominal voltages of 3.0 V, 3.3 V, and 5.0 V.

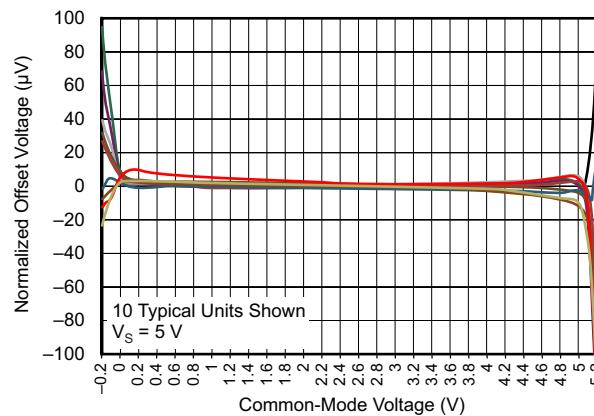
The TLV369 (single version) is offered in a 5-pin SC70 package. The TLV2369 (dual version) comes in 8-pin VSSOP and SOIC packages.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TLV369	SC70 (5)	2.00 mm x 1.25 mm
TLV2369	VSSOP (8)	3.00 mm x 3.00 mm
	SOIC (8)	4.90 mm x 3.91 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

## TLV369 Family Eliminates Crossover Distortion Across the Full Supply Range



An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. **PRODUCTION DATA**.

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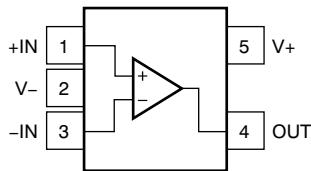
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## 4 Revision History

DATE	REVISION	NOTES
May 2016	*	Initial release.

## 5 Pin Configuration and Functions

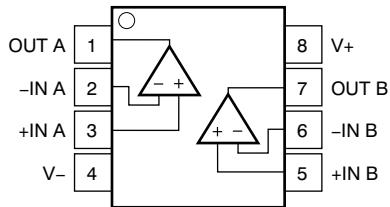
**TLV369: DCK Package  
5-Pin SC70  
Top View**



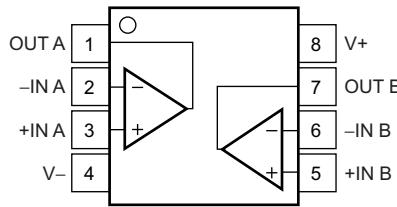
**Pin Functions: TLV369**

PIN		I/O	DESCRIPTION
NAME	TLV369 DCK (SC70)		
-IN	3	I	Negative (inverting) input
+IN	1	I	Positive (noninverting) input
OUT	4	O	Output
V-	2	—	Negative (lowest) power supply or ground (for single-supply operation)
V+	5	—	Positive (highest) power supply

**TLV2369: D Package  
8-Pin SOIC  
Top View**



**TLV2369: DGK Package  
8-Pin VSSOP  
Top View**



**Pin Functions: TLV2369**

PIN			I/O	DESCRIPTION
NAME	TLV2369	DGK (VSSOP)		
-IN A	2	2	I	Inverting input, channel A
-IN B	6	6	I	Inverting input, channel B
+IN A	3	3	I	Noninverting input, channel A
+IN B	5	5	I	Noninverting input, channel B
OUT A	1	1	O	Output, channel A
OUT B	7	7	O	Output, channel B
V-	4	4	—	Negative (lowest) power supply
V+	8	8	—	Positive (highest) power supply

## 6 Specifications

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Voltage	Supply, $V_S = (V+) - (V-)$	0	+7	V
	Signal input pin <sup>(2)</sup>	$(V-) - 0.5$	$(V+) + 0.5$	V
Current	Signal input pin <sup>(2)</sup>	-10	10	mA
	Output short-circuit <sup>(3)</sup>	Continuous		mA
Temperature	Operating, $T_A$	-40	125	°C
	Junction, $T_J$	150		°C
	Storage, $T_{stg}$	-65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) Input pins are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5 V beyond the supply rails must be current limited to 10 mA or less.
- (3) Short-circuit to  $V_S / 2$ , one amplifier per package.

### 6.2 ESD Ratings

over operating free-air temperature range (unless otherwise noted).

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	$\pm 4000$
		Charged device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	$\pm 1500$

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted).

		MIN	NOM	MAX	UNIT
$V_S$	Supply voltage	1.8		5.5	V
	Specified temperature	-40		85	°C

## 6.4 Thermal Information: TLV369

THERMAL METRIC <sup>(1)</sup>		TLV369	UNIT
		DCK (SC70)	
		5 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	293.3	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	95.2	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	83.4	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	2.9	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	82.4	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 6.5 Thermal Information: TLV2369

THERMAL METRIC <sup>(1)</sup>		TLV2369		UNIT
		D (SOIC)	DGK (VSSOP)	
		8 PINS	8 PINS	
R <sub>θJA</sub>	Junction-to-ambient thermal resistance	121.5	168.5	°C/W
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	66.3	58.1	°C/W
R <sub>θJB</sub>	Junction-to-board thermal resistance	62.5	88.9	°C/W
Ψ <sub>JT</sub>	Junction-to-top characterization parameter	22.8	9.3	°C/W
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	61.9	87.6	°C/W
R <sub>θJC(bot)</sub>	Junction-to-case (bottom) thermal resistance	n/a	n/a	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

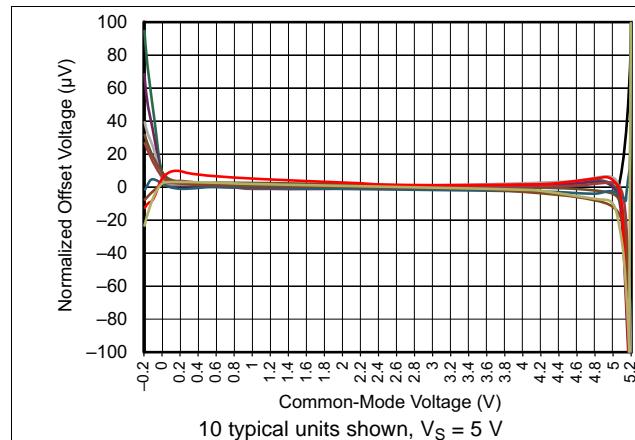
## 6.6 Electrical Characteristics

$V_S$  (total supply voltage) = 1.8 V to 5.5 V; at  $T_A = 25^\circ\text{C}$ , and  $R_L = 100 \text{ k}\Omega$  connected to  $V_S / 2$  (unless otherwise noted)

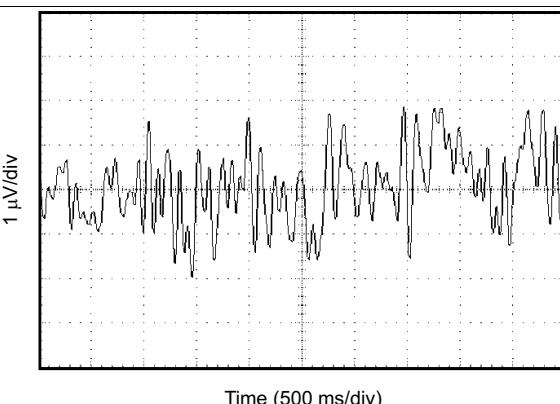
PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFFSET VOLTAGE</b>					
$V_{OS}$ Input offset voltage	At $T_A = 25^\circ\text{C}$		0.4	2	mV
	At $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		0.85		
$dV_{OS}/dT$ Drift	At $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		0.5		$\mu\text{V}/^\circ\text{C}$
PSRR Power-supply rejection ratio	$V_S = 1.8 \text{ V to } 5.5 \text{ V}$	80	94		dB
<b>INPUT VOLTAGE RANGE</b>					
$V_{CM}$ Common-mode voltage range		$V_-$	$V_+$		V
CMRR Common-mode rejection ratio	$(V_-) \leq V_{CM} \leq (V_+)$	80	110		dB
<b>INPUT BIAS CURRENT</b>					
$I_B$ Input bias current	At $T_A = 25^\circ\text{C}$		10		pA
	At $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		See Figure 8		
$I_{OS}$ Input offset current			10		pA
<b>INPUT IMPEDANCE</b>					
$Z_{ID}$ Differential			$10^{13} \parallel 3$		$\Omega \parallel \text{pF}$
$Z_{IC}$ Common-mode			$10^{13} \parallel 6$		$\Omega \parallel \text{pF}$
<b>NOISE</b>					
$E_n$ Input voltage noise	$f = 0.1 \text{ Hz to } 10 \text{ Hz}$		4		$\mu\text{V}_{\text{PP}}$
$e_n$ Input voltage noise density	$f = 1 \text{ kHz}$		300		$\text{nV}/\sqrt{\text{Hz}}$
$i_n$ Input current noise density	$f = 1 \text{ kHz}$		1		$\text{fA}/\sqrt{\text{Hz}}$
<b>OPEN-LOOP GAIN</b>					
$A_{OL}$ Open-loop voltage gain	At $V_S = 5.5 \text{ V}$ , $100 \text{ mV} \leq V_O \leq (V_+) - 100 \text{ mV}$ , $R_L = 100 \text{ k}\Omega$		130		dB
	At $V_S = 5.5 \text{ V}$ , $500 \text{ mV} \leq V_O \leq (V_+) - 500 \text{ mV}$ , $R_L = 10 \text{ k}\Omega$	80	120		
<b>OUTPUT</b>					
$V_O$ Voltage output swing from rail	$R_L = 10 \text{ k}\Omega$			25	mV
$I_{SC}$ Short-circuit current			10		mA
$C_{LOAD}$ Capacitive load drive			See Figure 10		
<b>FREQUENCY RESPONSE</b>					
GBP Gain bandwidth product			12		kHz
SR Slew rate	$G = 1$		0.005		$\text{V}/\mu\text{s}$
$t_{OR}$ Overload recovery time	$V_{IN} \times \text{gain} = V_S$		250		$\mu\text{s}$
<b>POWER SUPPLY</b>					
$V_S$ Specified voltage range		1.8	5.5		V
$I_Q$ Quiescent current	$I_O = 0 \text{ mA, at } V_S = 5.5 \text{ V}$	800	1300		nA
<b>TEMPERATURE</b>					
Specified range		-40	85		$^\circ\text{C}$
$T_A$ Operating range		-40	125		$^\circ\text{C}$

## 6.7 Typical Characteristics

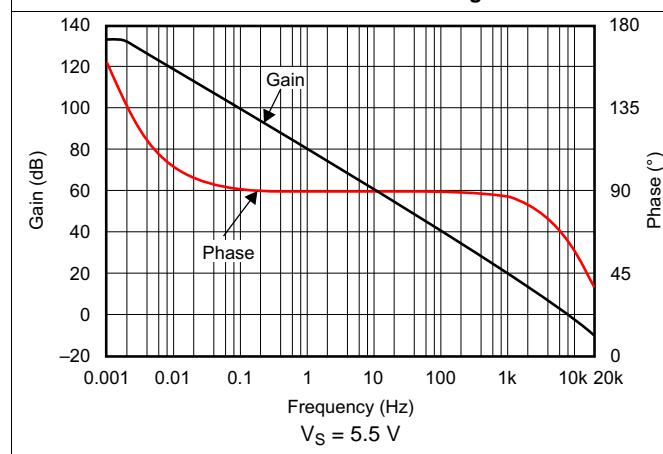
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $R_L = 100\text{ k}\Omega$  connected to  $V_S / 2$  (unless otherwise noted)



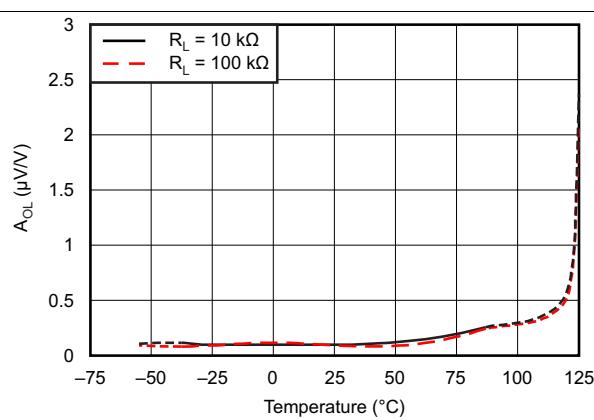
**Figure 1. Normalized Offset Voltage vs Common-Mode Voltage**



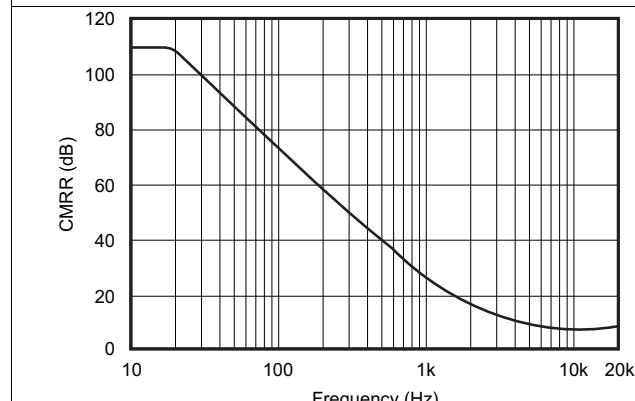
**Figure 2. 0.1-Hz to 10-Hz Noise**



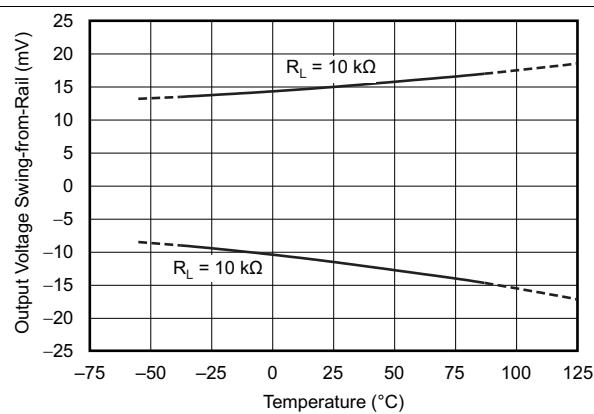
**Figure 3. Open-Loop Gain and Phase vs Frequency**



**Figure 4. Open-Loop Gain vs Temperature**



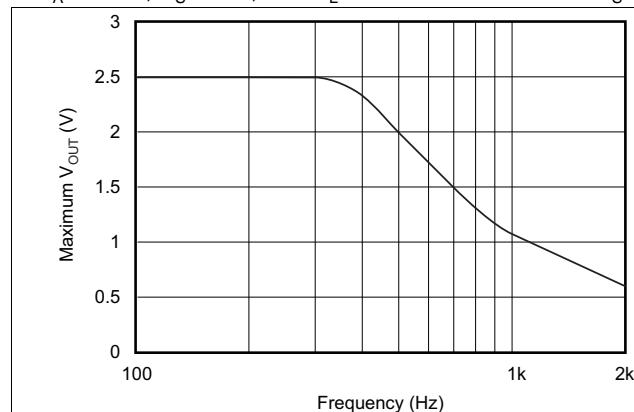
**Figure 5. Common-Mode Rejection Ratio vs Frequency**



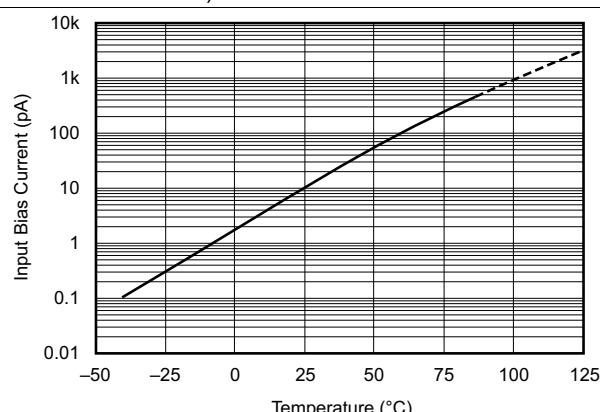
**Figure 6. Output Voltage Swing from Rail vs Temperature**

## Typical Characteristics (continued)

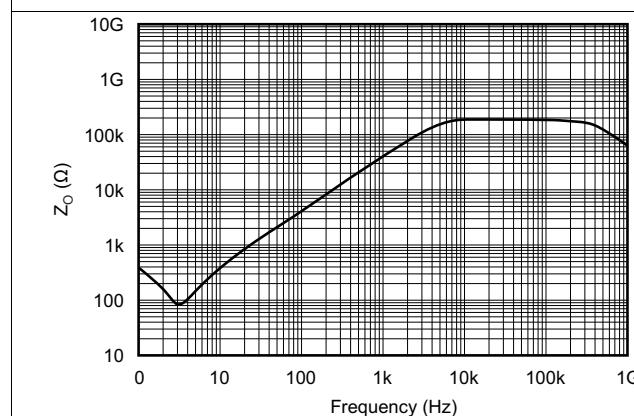
at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $R_L = 100\text{ k}\Omega$  connected to  $V_S / 2$  (unless otherwise noted)



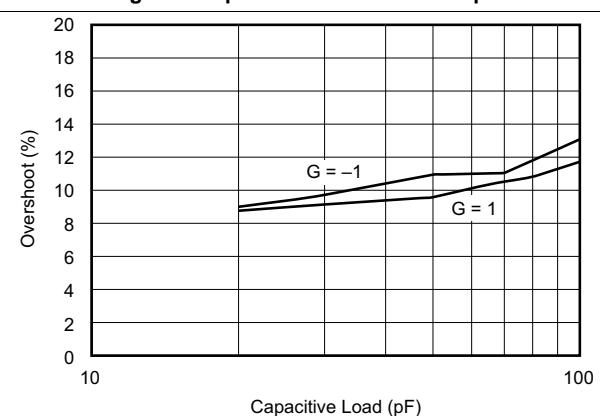
**Figure 7. Maximum Output Voltage vs Frequency**



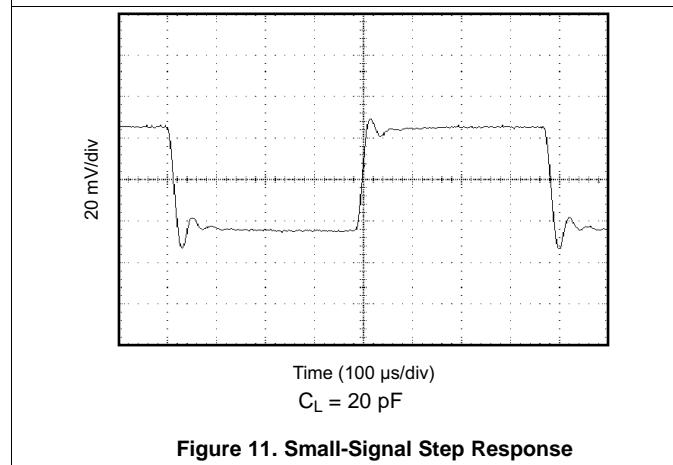
**Figure 8. Input Bias Current vs Temperature**



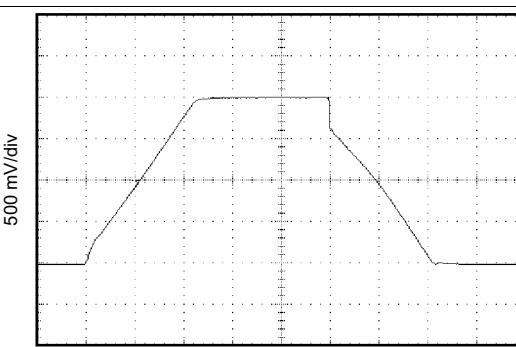
**Figure 9. Open-Loop Output Impedance vs Frequency**



**Figure 10. Small-Signal Overshoot vs Capacitive Load**



**Figure 11. Small-Signal Step Response**



**Figure 12. Large-Signal Step Response**

## Typical Characteristics (continued)

at  $T_A = 25^\circ\text{C}$ ,  $V_S = 5\text{ V}$ , and  $R_L = 100\text{ k}\Omega$  connected to  $V_S / 2$  (unless otherwise noted)

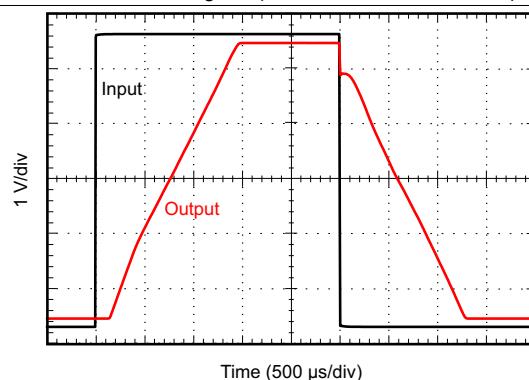


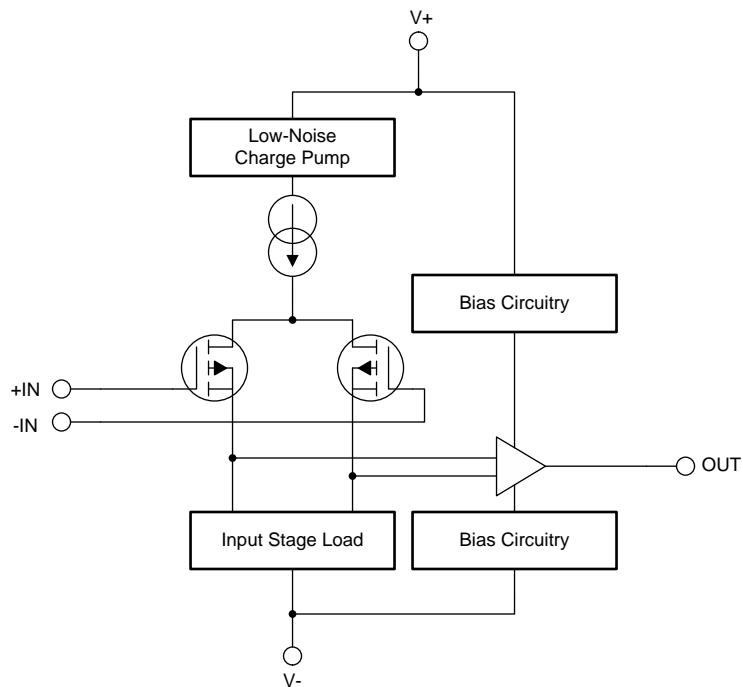
Figure 13. Overload Recovery

## 7 Detailed Description

### 7.1 Overview

The TLVx369 family of operational amplifiers minimizes power consumption and operates on supply voltages as low as 1.8 V. The zero-crossover distortion circuitry enables high linearity over the full input common-mode range, achieving true rail-to-rail input from a 1.8-V to 5.5-V single supply.

### 7.2 Functional Block Diagram



## 7.3 Feature Description

### 7.3.1 Operating Voltage

The TLV369 series of op amps are fully specified and tested from 1.8 V to 5.5 V ( $\pm 0.9$  V to  $\pm 2.75$  V). Parameters that vary significantly with supply voltage are described in the *Typical Characteristics* section.

### 7.3.2 Input Common-Mode Voltage Range

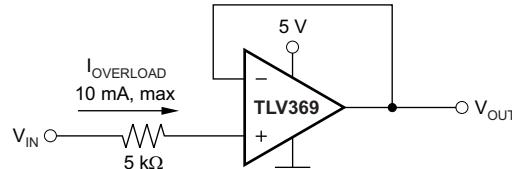
The TLV369 family is designed to eliminate the input offset transition region typically present in most rail-to-rail, complementary-stage operational amplifiers, allowing the TLV369 family of amplifiers to provide superior common-mode performance over the entire input range.

The input common-mode voltage range of the TLV369 family typically extends to each supply rail. CMRR is specified from the negative rail to the positive rail; see [Figure 1, Normalized Offset Voltage vs Common-Mode Voltage](#).

### 7.3.3 Protecting Inputs from Overvoltage

Input currents are typically 10 pA. However, large inputs (greater than 500 mV beyond the supply rails) can cause excessive current to flow in or out of the input pins. Therefore, in addition to keeping the input voltage between the supply rails, the input current must also be limited to less than 10 mA. This limiting is easily accomplished with an input resistor, as shown in [Figure 14](#).

A current-limiting resistor is required if the input voltage exceeds the supply rails by  $\geq 0.5$  V.



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**Figure 14. Input Current Protection for Voltages That Exceed the Supply Voltage**

## 7.4 Device Functional Modes

The TLV369 family has a single functional mode. These devices are powered on as long as the power-supply voltage is between 1.8 V ( $\pm 0.9$  V) and 5.5 V ( $\pm 2.75$  V).

## 8 Application and Implementation

### NOTE

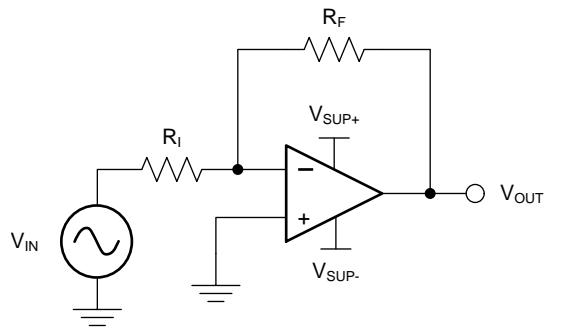
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 8.1 Application Information

When designing for ultra-low power, choose system components carefully. To minimize current consumption, select large-value resistors. Any resistors can react with stray capacitance in the circuit and the input capacitance of the operational amplifier. These parasitic RC combinations can affect the stability of the overall system. Use of a feedback capacitor assures stability and limits overshoot or gain peaking.

### 8.2 Typical Application

A typical application for an operational amplifier is an inverting amplifier, as shown in [Figure 15](#). An inverting amplifier takes a positive voltage on the input and outputs a signal inverted to the input, making a negative voltage of the same magnitude. In the same manner, the amplifier also makes negative input voltages positive on the output. In addition, amplification can be added by selecting the input resistor  $R_I$  and the feedback resistor  $R_F$ .



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**Figure 15. Application Schematic**

#### 8.2.1 Design Requirements

The supply voltage must be chosen to be larger than the input voltage range and the desired output range. The limits of the input common-mode range ( $V_{CM}$ ) and the output voltage swing to the rails ( $V_O$ ) must also be considered. For instance, this application scales a signal of  $\pm 0.5$  V (1 V) to  $\pm 1.8$  V (3.6 V). Setting the supply at  $\pm 2.5$  V is sufficient to accommodate this application.

## Typical Application (continued)

### 8.2.2 Detailed Design Procedure

Determine the gain required by the inverting amplifier using [Equation 1](#) and [Equation 2](#):

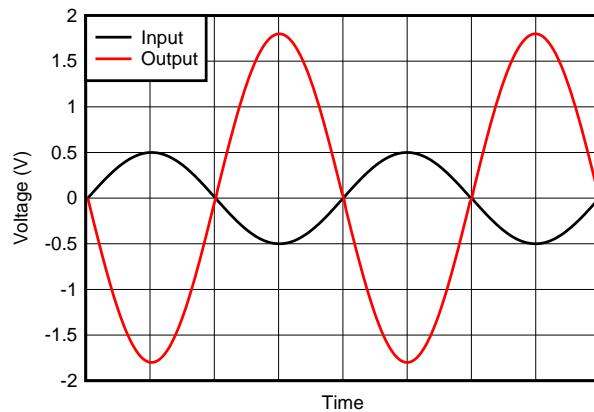
$$A_V = \frac{V_{OUT}}{V_{IN}} \quad (1)$$

$$A_V = \frac{1.8}{-0.5} = -3.6 \quad (2)$$

When the desired gain is determined, choose a value for  $R_I$  or  $R_F$ . Choosing a value in the kilohm range is desirable for general-purpose applications because the amplifier circuit uses currents in the milliamp range. This milliamp current range ensures that the device does not draw too much current. The trade-off is that very large resistors (100s of kilohms) draw the smallest current but generate the highest noise. Very small resistors (100s of ohms) generate low noise but draw high current. This example uses 10 k $\Omega$  for  $R_I$ , meaning 36 k $\Omega$  is used for  $R_F$ . These values are determined by [Equation 3](#):

$$A_V = -\frac{R_F}{R_I} \quad (3)$$

### 8.2.3 Application Curve

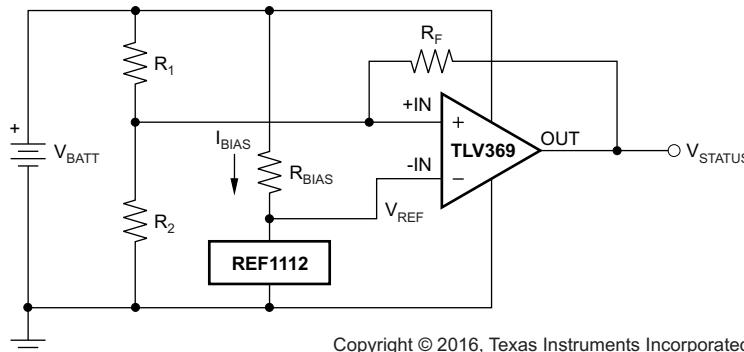


**Figure 16. Inverting Amplifier Input and Output**

## 8.3 System Examples

### 8.3.1 Battery Monitoring

The low operating voltage and quiescent current of the TLV369 series make the family an excellent choice for battery-monitoring applications, as shown in [Figure 17](#).



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**Figure 17. Battery Monitor**

In this circuit,  $V_{\text{STATUS}}$  is high as long as the battery voltage remains above 2 V. A low-power reference is used to set the trip point. Resistor values are selected as follows:

1. Selecting  $R_F$ : Select  $R_F$  such that the current through  $R_F$  is approximately 1000 times larger than the maximum bias current over temperature, as given by [Equation 4](#):

$$\begin{aligned}
 R_F &= \frac{V_{\text{REF}}}{1000 (I_{\text{BMAX}})} \\
 &= \frac{1.2 \text{ V}}{1000 (50 \text{ pA})} \\
 &= 24 \text{ M}\Omega \approx 20 \text{ M}\Omega
 \end{aligned} \tag{4}$$

2. Choose the hysteresis voltage,  $V_{\text{HYST}}$ . For battery-monitoring applications, 50 mV is adequate.

3. Calculate  $R_1$  as calculated by [Equation 5](#):

$$R_1 = R_F \left( \frac{V_{\text{HYST}}}{V_{\text{BATT}}} \right) = 20 \text{ M}\Omega \left( \frac{50 \text{ mV}}{2.4 \text{ V}} \right) = 420 \text{ k}\Omega \tag{5}$$

4. Select a threshold voltage for  $V_{\text{IN}}$  rising ( $V_{\text{THRS}}$ ) = 2.0 V.

5. Calculate  $R_2$  as given by [Equation 6](#):

$$\begin{aligned}
 R_2 &= \frac{1}{\left( \left( \frac{V_{\text{THRS}}}{V_{\text{BATT}}} \right) - \frac{1}{R_1} - \frac{1}{R_F} \right)} \\
 &= \frac{1}{\left( \left( \frac{2 \text{ V}}{1.2 \text{ V} \times 420 \text{ k}\Omega} \right) - \frac{1}{420 \text{ k}\Omega} - \frac{1}{20 \text{ M}\Omega} \right)} \\
 &= 650 \text{ k}\Omega
 \end{aligned} \tag{6}$$

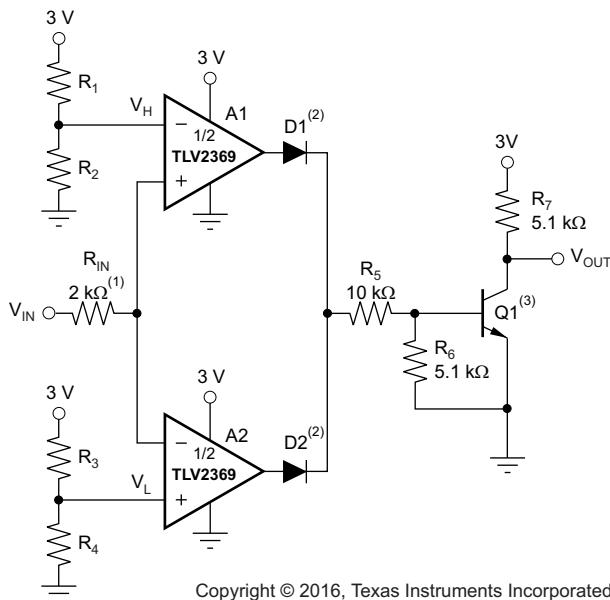
6. Calculate  $R_{\text{BIAS}}$ : The minimum supply voltage for this circuit is 1.8 V. The REF1112 has a current requirement of 1.2  $\mu\text{A}$  (max). Providing the REF1112 with 2  $\mu\text{A}$  of supply current assures proper operation. Therefore,  $R_{\text{BIAS}}$  is as given by [Equation 7](#).

$$R_{\text{BIAS}} = \frac{V_{\text{BATTMIN}}}{I_{\text{BIAS}}} = \frac{1.8 \text{ V}}{2 \mu\text{A}} = 0.9 \text{ M}\Omega \tag{7}$$

## System Examples (continued)

### 8.3.2 Window Comparator

Figure 18 shows the TLV2369 used as a window comparator. The threshold limits are set by  $V_H$  and  $V_L$ , with  $V_H$  greater than  $V_L$ . When  $V_{IN}$  is less than  $V_L$ , the output of A1 is low. When  $V_{IN}$  is greater than  $V_H$ , the output of A2 is low. Therefore, both op amp outputs are at 0 V as long as  $V_{IN}$  is between  $V_H$  and  $V_L$ . This architecture results in no current flowing through either diode, Q1 is in cutoff, with the base voltage at 0 V, and  $V_{OUT}$  forced high.



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**Figure 18. TLV2369 as a Window Comparator**

If  $V_{IN}$  falls below  $V_L$ , the output of A2 is high, current flows through D2, and  $V_{OUT}$  is low. Likewise, if  $V_{IN}$  rises above  $V_H$ , the output of A1 is high, current flows through D1, and  $V_{OUT}$  is low. The window comparator threshold voltages are set as shown by [Equation 8](#) and [Equation 9](#):

$$V_H = \frac{R_2}{R_1 + R_2} \quad (8)$$

$$V_L = \frac{R_4}{R_3 + R_4} \quad (9)$$

## 9 Power Supply Recommendations

The TLV369 family is specified for operation from 1.8 V to 5.5 V ( $\pm 0.9$  V to  $\pm 2.75$  V); many specifications apply from  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ . The [Typical Characteristics](#) section presents parameters that can exhibit significant variance with regard to operating voltage or temperature.

### CAUTION

Supply voltages larger than 7 V can permanently damage the device (see the [Absolute Maximum Ratings](#) table).

Place 0.1- $\mu\text{F}$  bypass capacitors close to the power-supply pins to reduce errors coupling in from noisy or high-impedance power supplies. For more detailed information on bypass capacitor placement; see the [Layout Guidelines](#) section.

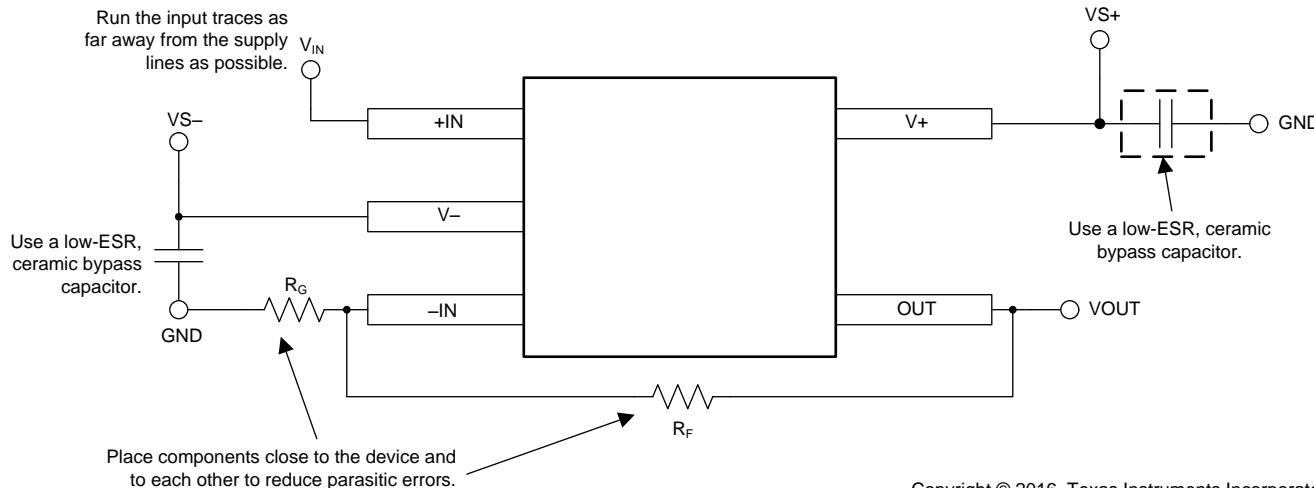
## 10 Layout

### 10.1 Layout Guidelines

For best operational performance of the device, use good printed circuit board (PCB) layout practices, including:

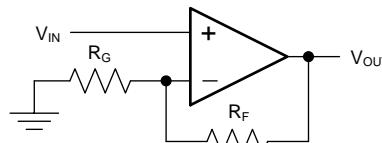
- Noise can propagate into analog circuitry through the power pins of the circuit as a whole and the operational amplifier. Use bypass capacitors to reduce the coupled noise by providing low-impedance power sources local to the analog circuitry.
  - Connect low-ESR, 0.1- $\mu$ F ceramic bypass capacitors between each supply pin and ground, placed as close to the device as possible. A single bypass capacitor from V+ to ground is applicable for single-supply applications.
- Separate grounding for analog and digital portions of the circuitry is one of the simplest and most effective methods of noise suppression. One or more layers on multilayer PCBs are usually devoted to ground planes. A ground plane helps distribute heat and reduces electromagnetic interference (EMI) noise pickup. Make sure to physically separate digital and analog grounds, paying attention to the flow of the ground current. For more detailed information, see *Circuit Board Layout Techniques*, **SLOA089**.
- To reduce parasitic coupling, run the input traces as far away from the supply or output traces as possible. If these traces cannot be kept separate, crossing the sensitive trace perpendicularly is much better than crossing in parallel with the noisy trace.
- Place the external components as close to the device as possible. Keep  $R_F$  and  $R_G$  close to the inverting input in order to minimize parasitic capacitance, as shown in [Figure 19](#).
- Keep the length of input traces as short as possible. Always remember that the input traces are the most sensitive part of the circuit.
- Consider a driven, low-impedance guard ring around the critical traces. A guard ring can significantly reduce leakage currents from nearby traces that are at different potentials.

### 10.2 Layout Example



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**Figure 19. Operational Amplifier Board Layout for Noninverting Configuration**



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**Figure 20. Schematic Representation of Figure 19**

## 11 Device and Documentation Support

### 11.1 Documentation Support

#### 11.1.1 Related Documentation

The following documents are relevant to using the TLVx369, and are recommended for reference and available for download at [www.ti.com](http://www.ti.com), unless otherwise noted.

- REF1112 Data Sheet, [SBOS283](#)
- *Circuit Board Layout Techniques*, [SLOA089](#)
- *Handbook of Operational Amplifier Applications*, [SBOA092](#)
- *Analog Engineer's Pocket Reference*, [SLWY038](#)

#### 11.1.1.1 Related Links

Table 1 lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

**Table 1. Related Links**

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
TLV369	<a href="#">Click here</a>				
TLV2369	<a href="#">Click here</a>				

### 11.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

**TI E2E™ Online Community** *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At [e2e.ti.com](http://e2e.ti.com), you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

**Design Support** *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 11.3 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

### 11.4 Electrostatic Discharge Caution

 This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

 ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 11.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLV2369IDGKR	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	13JV
TLV2369IDGKR.A	Active	Production	VSSOP (DGK)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	13JV
TLV2369IDGKT	Active	Production	VSSOP (DGK)   8	250   SMALL T&R	Yes	NIPDAU   NIPDAUAG	Level-2-260C-1 YEAR	-40 to 125	13JV
TLV2369IDGKT.A	Active	Production	VSSOP (DGK)   8	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	13JV
TLV2369IDR	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2369
TLV2369IDR.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2369
TLV2369IDRG4	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2369
TLV2369IDRG4.A	Active	Production	SOIC (D)   8	2500   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TL2369
TLV369IDCKR	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 125	12K
TLV369IDCKR.A	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12K
TLV369IDCKR.B	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12K
TLV369IDCKT	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU   SN	Level-2-260C-1 YEAR	-40 to 125	12K
TLV369IDCKT.A	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12K
TLV369IDCKT.B	Active	Production	SC70 (DCK)   5	250   SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	12K

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

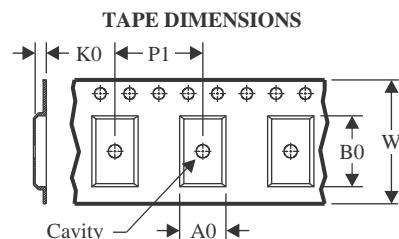
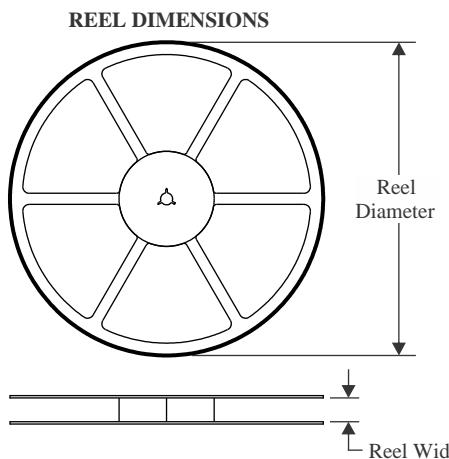
<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

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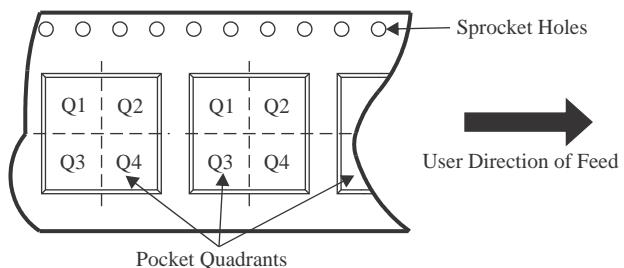
Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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**TAPE AND REEL INFORMATION**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2369IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2369IDGKT	VSSOP	DGK	8	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2369IDGKT	VSSOP	DGK	8	250	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2369IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2369IDRG4	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV369IDCKR	SC70	DCK	5	3000	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3
TLV369IDCKT	SC70	DCK	5	250	180.0	8.4	2.3	2.5	1.2	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2369IDGKR	VSSOP	DGK	8	2500	353.0	353.0	32.0
TLV2369IDGKT	VSSOP	DGK	8	250	366.0	364.0	50.0
TLV2369IDGKT	VSSOP	DGK	8	250	353.0	353.0	32.0
TLV2369IDR	SOIC	D	8	2500	353.0	353.0	32.0
TLV2369IDRG4	SOIC	D	8	2500	353.0	353.0	32.0
TLV369IDCKR	SC70	DCK	5	3000	210.0	185.0	35.0
TLV369IDCKT	SC70	DCK	5	250	210.0	185.0	35.0

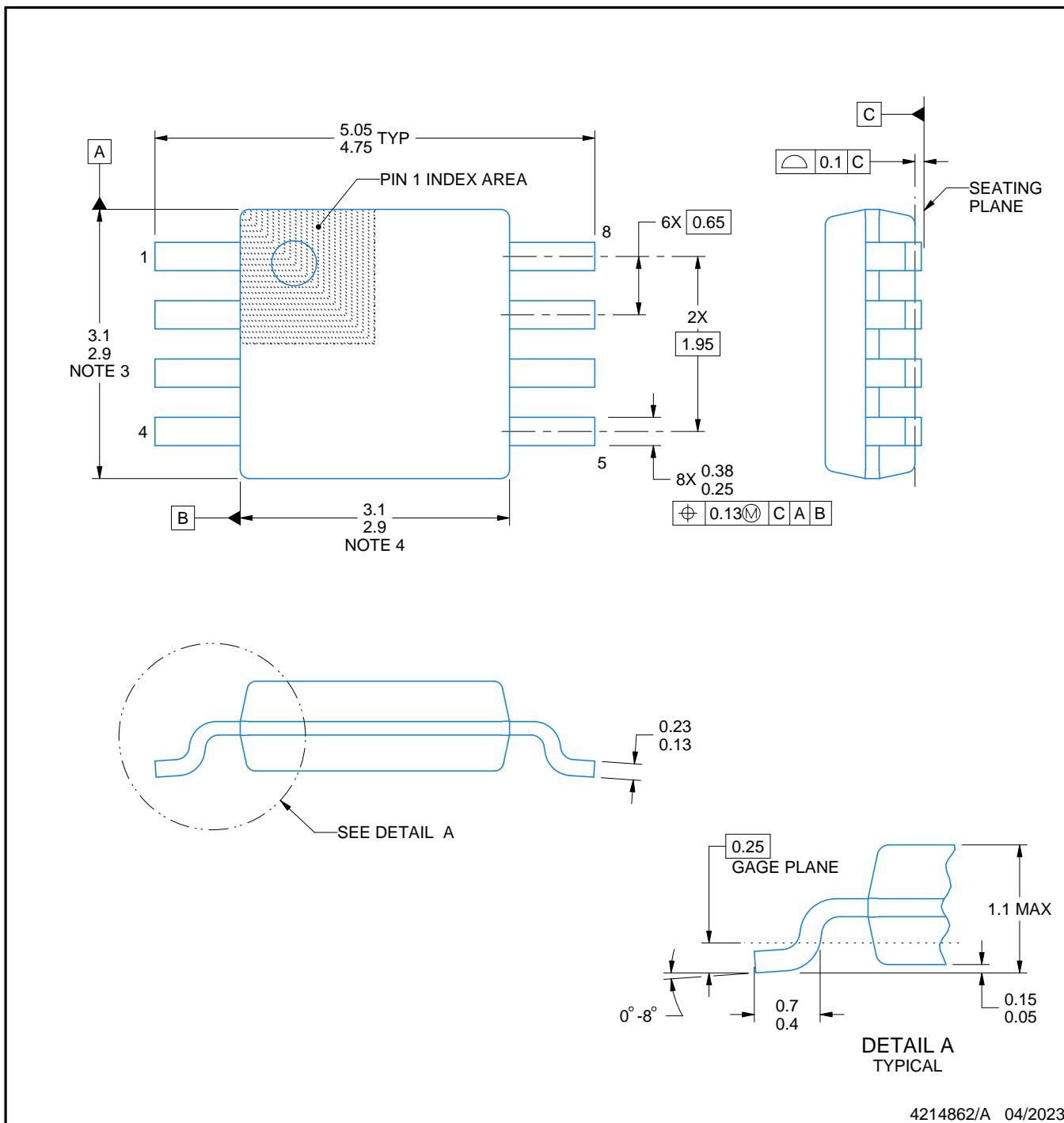
# PACKAGE OUTLINE

DGK0008A



VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

PowerPAD is a trademark of Texas Instruments.

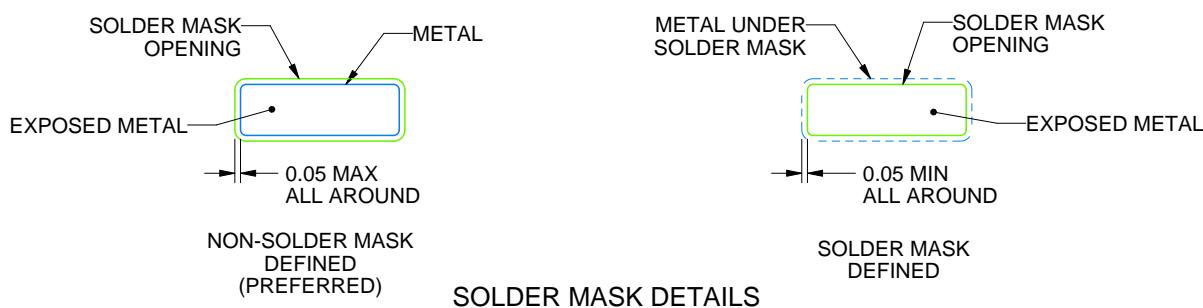
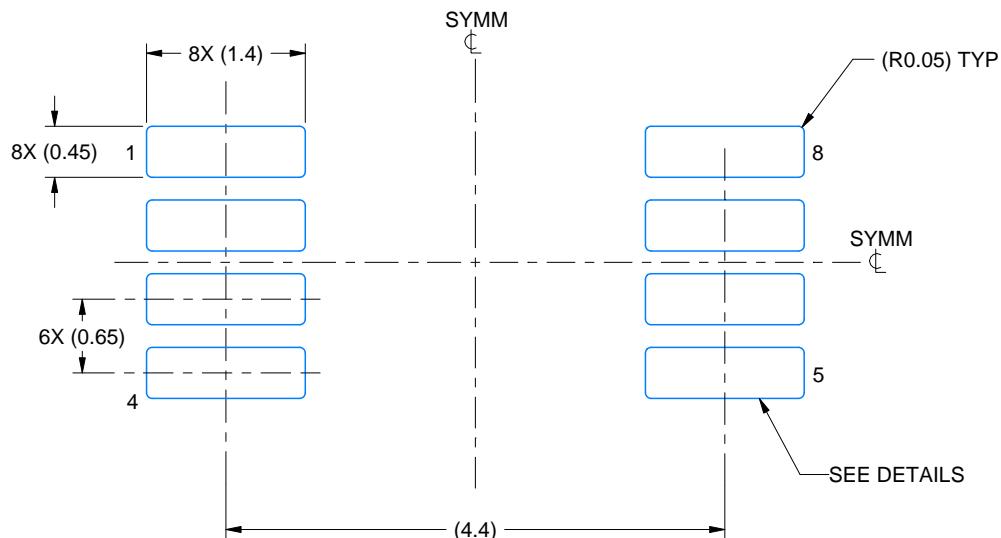
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-187.

# EXAMPLE BOARD LAYOUT

DGK0008A

™ VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



4214862/A 04/2023

NOTES: (continued)

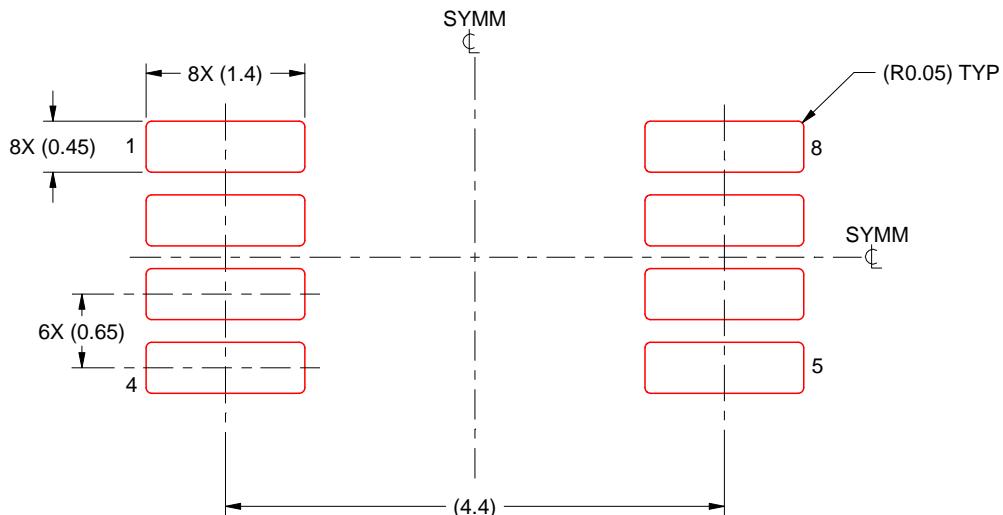
6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
8. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.
9. Size of metal pad may vary due to creepage requirement.

# EXAMPLE STENCIL DESIGN

DGK0008A

TM VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE  
SCALE: 15X

4214862/A 04/2023

NOTES: (continued)

11. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
12. Board assembly site may have different recommendations for stencil design.

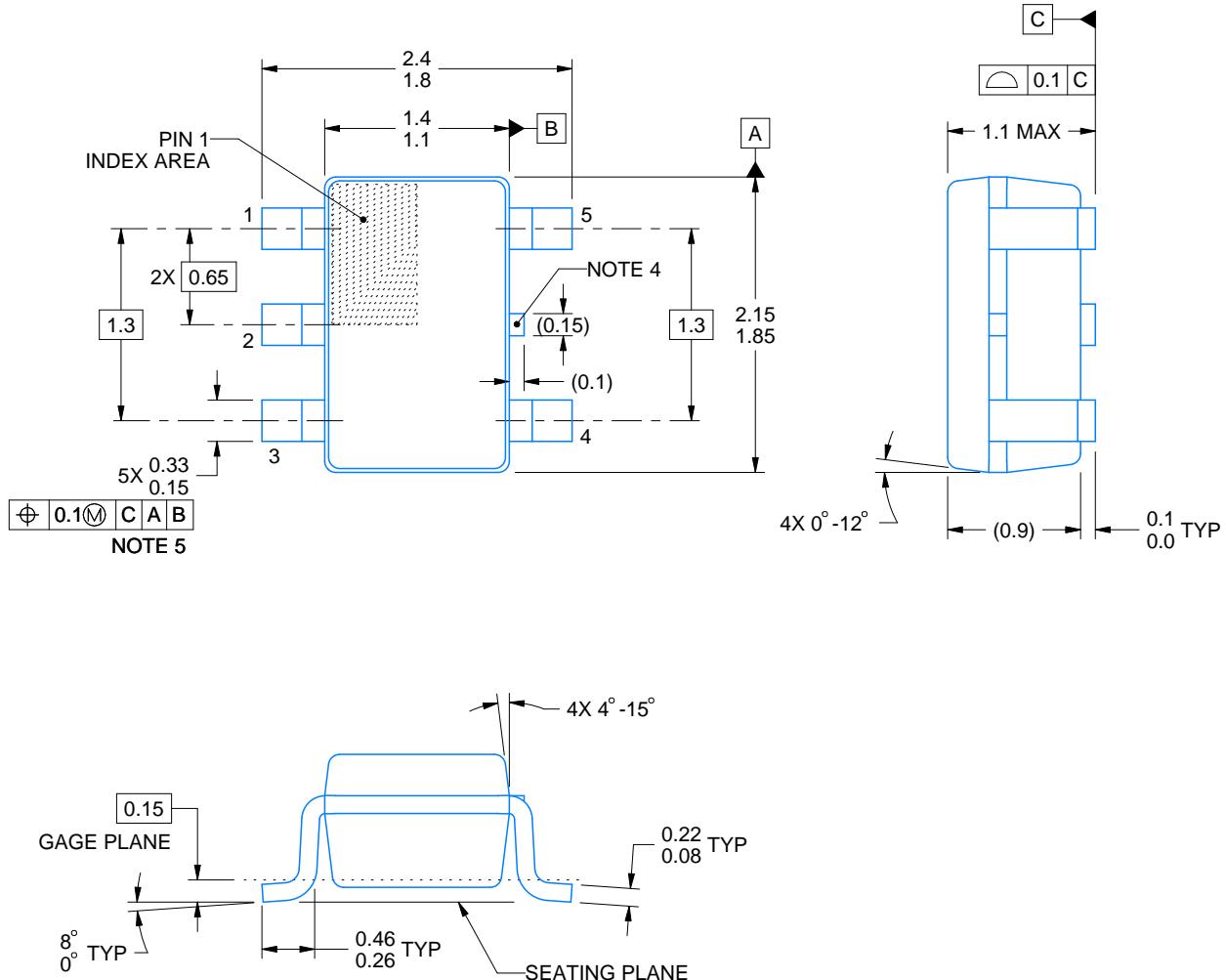
## PACKAGE OUTLINE

**DCK0005A**



## SOT - 1.1 max height

## SMALL OUTLINE TRANSISTOR



## NOTES:

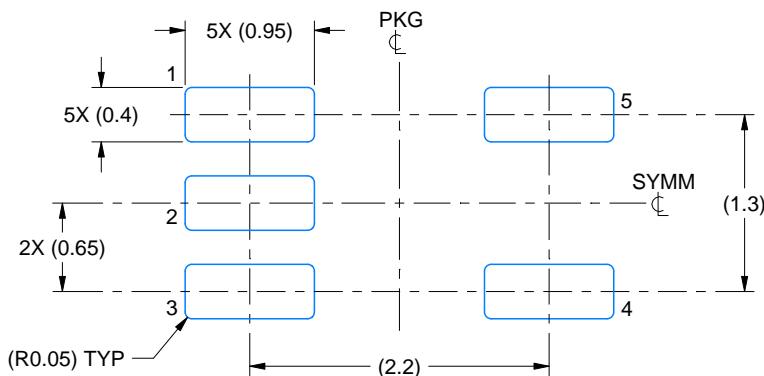
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC MO-203.
4. Support pin may differ or may not be present.
5. Lead width does not comply with JEDEC.
6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side

# EXAMPLE BOARD LAYOUT

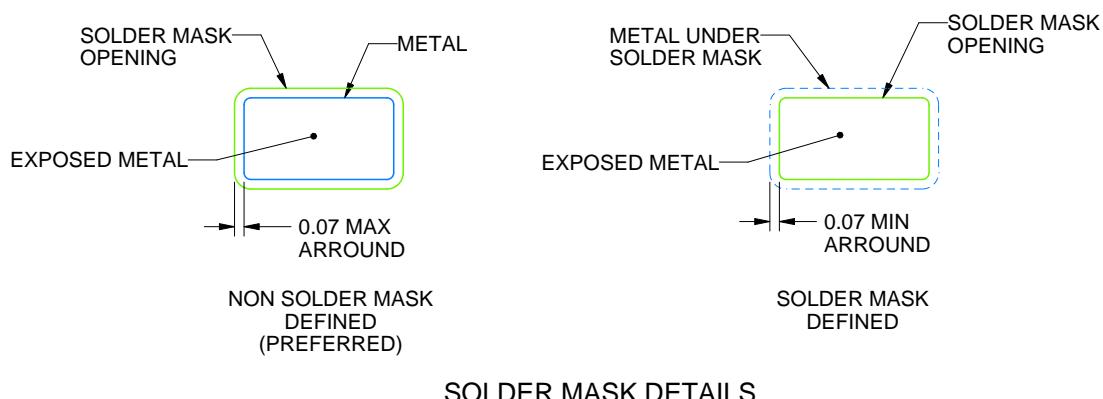
DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:18X



4214834/G 11/2024

NOTES: (continued)

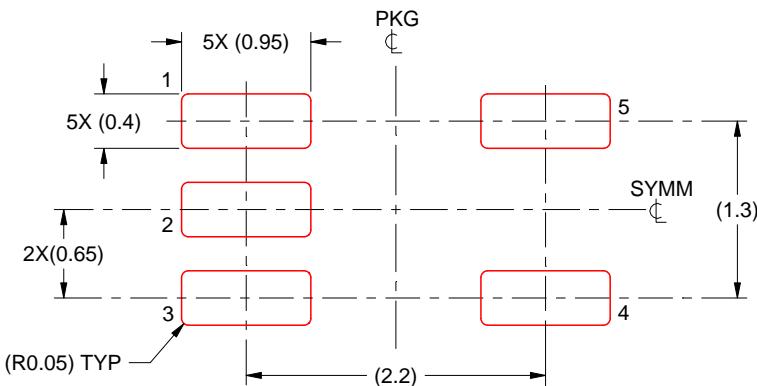
7. Publication IPC-7351 may have alternate designs.
8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DCK0005A

SOT - 1.1 max height

SMALL OUTLINE TRANSISTOR



SOLDER PASTE EXAMPLE  
BASED ON 0.125 THICK STENCIL  
SCALE:18X

4214834/G 11/2024

NOTES: (continued)

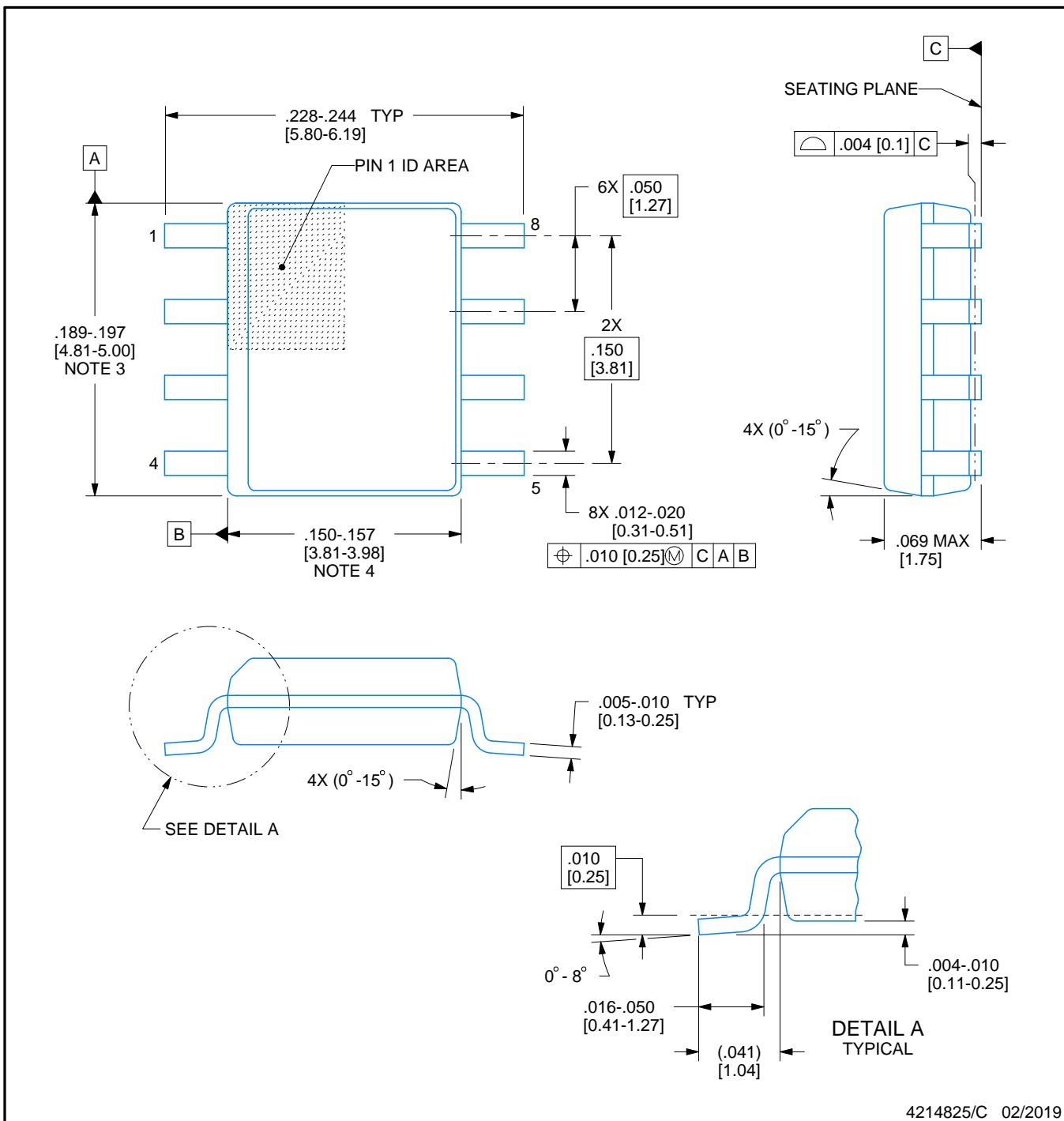
9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
10. Board assembly site may have different recommendations for stencil design.



# PACKAGE OUTLINE

## SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



### NOTES:

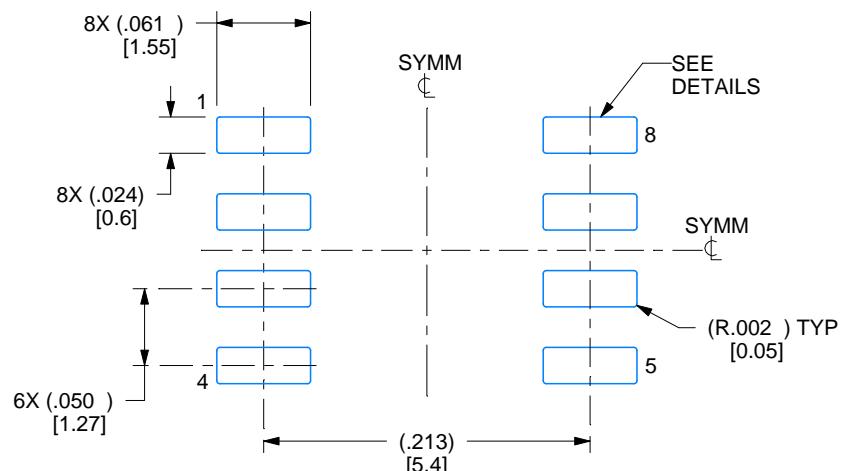
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

# EXAMPLE BOARD LAYOUT

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE  
BASED ON .005 INCH [0.125 MM] THICK STENCIL  
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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